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·	Application No.	Applicant(s)	
Nation of Allowability	10/626,248	LEE, JAE-KYU	
Notice of Allowability	Examiner	Art Unit	
	Christian Wilson	2824	
The MAILING DATE of this communication app All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT F of the Office or upon petition by the applicant. See 37 CFR 1.31	S (OR REMAINS) CLOSED in S) or other appropriate commu RIGHTS. This application is s	this application. If not included nication will be mailed in due course.	. THIS e initiative
1. This communication is responsive to			
2. The allowed claim(s) is/are <u>1-20</u> .			
3. \boxtimes The drawings filed on <u>23 July 2003</u> are accepted by the E	xaminer.		
 4. Acknowledgment is made of a claim for foreign priority of a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received: 	re been received. re been received in Applicatio	n No	m the
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONI THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		a reply complying with the requireme	ents
5. A SUBSTITUTE OATH OR DECLARATION must be subr INFORMAL PATENT APPLICATION (PTO-152) which give	nitted. Note the attached EXA ves reason(s) why the oath or	MINER'S AMENDMENT or NOTICE declaration is deficient.	OF
6. CORRECTED DRAWINGS (as "replacement sheets") mu	st be submitted.		
(a) I including changes required by the Notice of Draftsper	son's Patent Drawing Review	(PTO-948) attached	
1) 🗌 hereto or 2) 🔲 to Paper No./Mail Date	<u>_</u> .		
(b) ☐ including changes required by the attached Examiner Paper No./Mail Date	's Amendment / Comment or	in the Office action of	
Identifying indicia such as the application number (see 37 CFR each sheet. Replacement sheet(s) should be labeled as such in	1.84(c)) should be written on th the header according to 37 CFI	e drawings in the front (not the back) o R 1.121(d).	of
 DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT 	osit of BIOLOGICAL MATE FOR THE DEPOSIT OF BIC	RIAL must be submitted. Note the LOGICAL MATERIAL.	e
Attachment(s) 1. ☑ Notice of References Cited (PTO-892)	E Motion of Inf	ormal Datant Application (DTO 152)	
Notice of Preferences Cited (FTO-692) Notice of Draftperson's Patent Drawing Review (PTO-948)		ormal Patent Application (PTO-152) mmary (PTO-413),	
3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/	Paper No./I	Mail Date Amendment/Comment	
Paper No./Mail Date 4. ☐ Examiner's Comment Regarding Requirement for Deposit	8 □ Evaminer's	Statement of Reasons for Allowance	
of Biological Material	9. ⊠ Other <u>search</u>		
. •	-: <u>23</u> - (110) - <u>500/01</u>	Malul Chillet	
•	Î	MICHAEL S. LEBENTRITT	
		PRIMARY EXAMINER	

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EXAMINER'S AMENDMENT

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1. Claims 1 - 20 are allowed.

2. An examiner's amendment to the record appears below. Should the changes and/or

additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR

1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the

payment of the issue fee.

The application has been amended as follows: replace the abstract with the following -

A method for forming a shallow well of a semiconductor device using low-energy ion

implantation is described. A well region is formed to the depth of a trench isolation layer using a

low-energy, high-dose ion implantation process. The method for forming a well using low-

energy ion implantation can minimize well margin reduction caused by impurity spread and well

margin reduction caused by shrinkage of a thick photoresist pattern.

3. The following is an examiner's statement of reasons for allowance: applicant discloses a

novel method of forming a well where, in the context of the entire claim, an isolation trench is

formed, a first ion implantation is performed, the trench is filled, and a second ion implantation

is formed at a higher energy level than the first ion implantation and a lower dose than the first

dose.

Any comments considered necessary by applicant must be submitted no later than the

payment of the issue fee and, to avoid processing delays, should preferably accompany the issue

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fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for

Allowance."

A copy of the search history (EAST and STN) is enclosed. 4.

5. The prior art made of record and not relied upon is considered pertinent to applicant's

disclosure. The cited prior art teaches methods of forming a well with implantation before and

after the formation of the shallow trench isolation, but without a higher energy, lower dose

second implantation.

CDW

Any inquiry concerning this communication or earlier communications from the 6.

examiner should be directed to Christian Wilson whose telephone number is (571) 272-1886.

The examiner can normally be reached on weekdays, 7:30 AM to 4 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Richard Elms can be reached on (571) 272-1869. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Christian Wilson, Ph.D.

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Patent Examiner

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SAME TO THE PARTY OF THE PARTY MICHAEL S. LEBENTRITT

PRIMARY EXAMINER